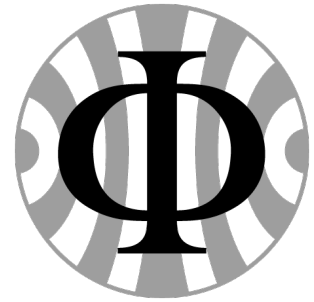


MuPix10: First Results from the Final Design

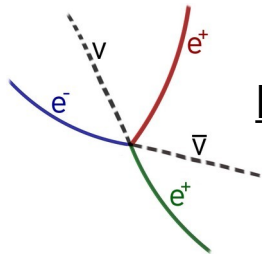
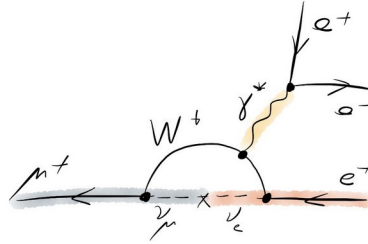
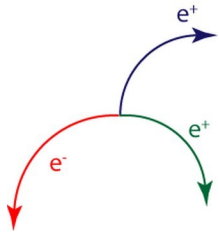


Heiko Augustin on behalf of the Mu3e pixel team
Physikalisches Institut Heidelberg

Vertex2020

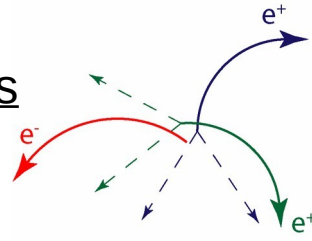
07.10.2020

Mu3e



Backgrounds

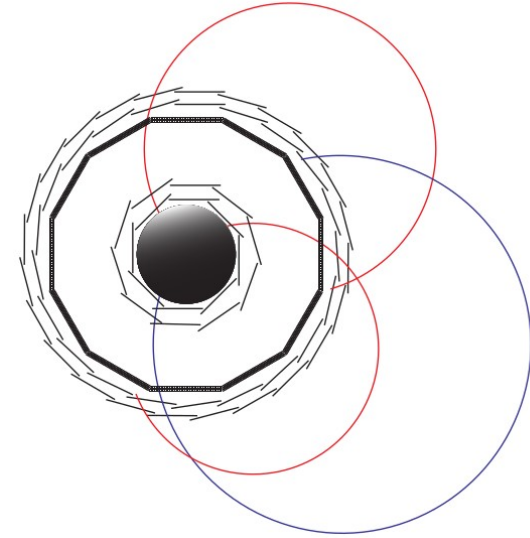
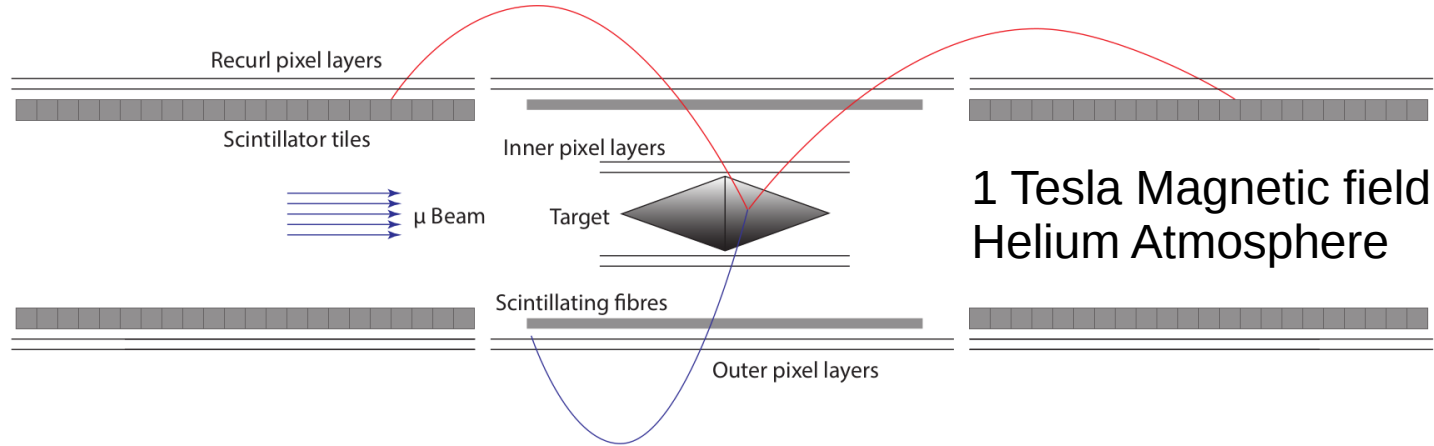
Internal Conversion



Accidental

- Search for the cLFV decay
 $\mu^+ \rightarrow e^+e^-e^+$
(ν SM: BR < 10^{-54})
- Current limit (SINDRUM)
BR < 10^{-12} @ 90% CL
- Sensitivity goal:
1 in 10^{16} decays
- Up to 10^9 decays per second
- Suppress background below
sensitivity level

The Mu3e Detector



- 10^8 - 10^9 decays per second
- $p_{\text{max}} = m_{\mu}/2 = 53 \text{ MeV}$
- Multiple Coulomb Scattering
- Good vertex and time resolution ($100 \text{ } \mu\text{m}$ & 500 ps)
- Good momentum resolution (0.5 MeV)
- Continuous Beam! No trigger!
- Online reconstruction and selection

The Mu3e Detector

Pixel detector requirements:

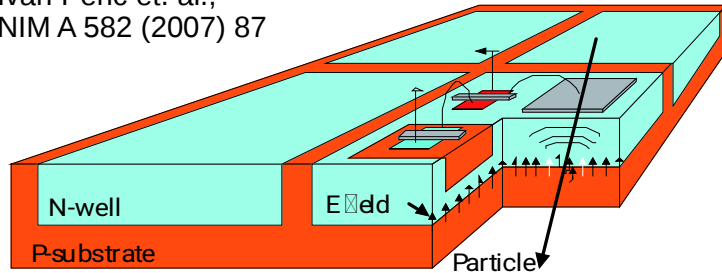
Pixel Size	Time Resolution	Material Budget	Efficiency
80 x 80 μm^2	< 20 ns	0.1% X_0 /layer	> 99 %

Mu3e TDR [arXiv:2009.11690]

- 10^8 - 10^9 decays per second
- $p_{\text{max}} = m_{\mu}/2 = 53 \text{ MeV}$
- Multiple Coulomb Scattering
- Good vertex and time resolution (100 μm & 500 ps)
- Good momentum resolution (0.5 MeV)
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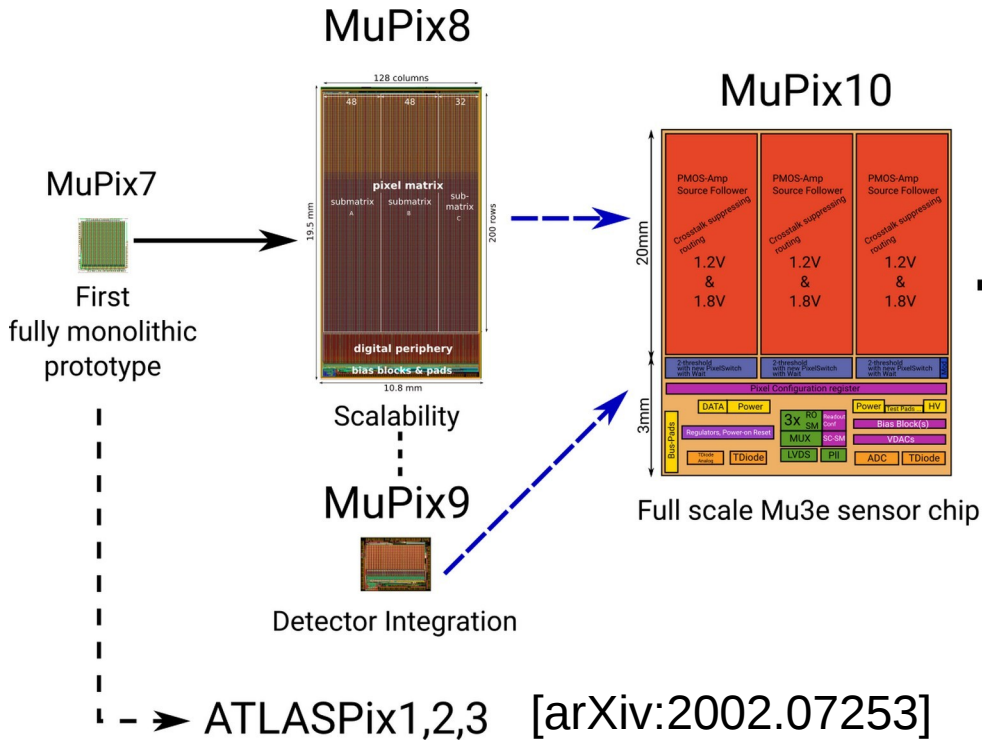
High Voltage - Monolithic Active Pixel Sensors

Ivan Peric et. al.,
NIM A 582 (2007) 87



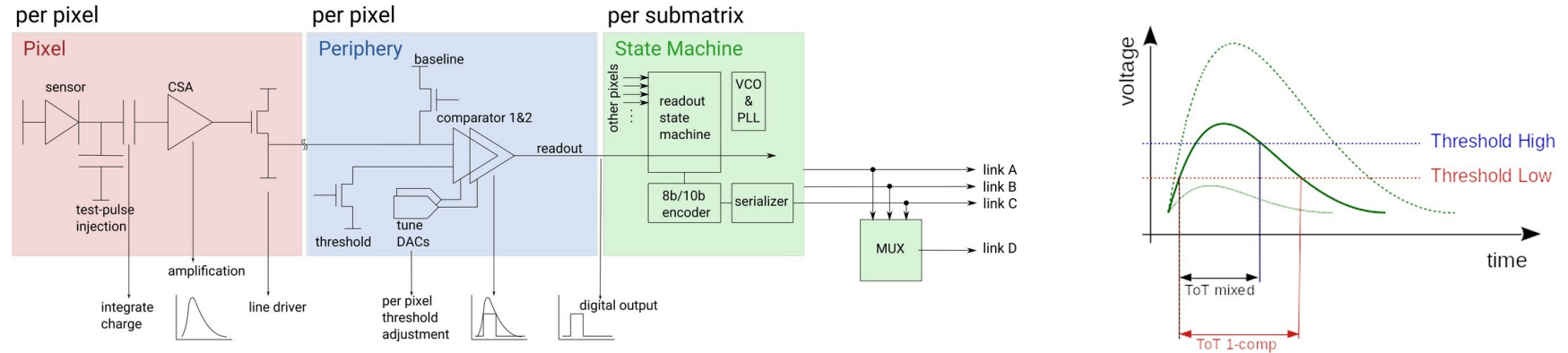
- In-pixel electronics
- Monolithic design:
Detection and Readout
combined in one chip
- Commercially available processes:
AMS 180nm (6M)
TSI 180nm (7M)
- Chips are thinned to 50 μm

MuPix History



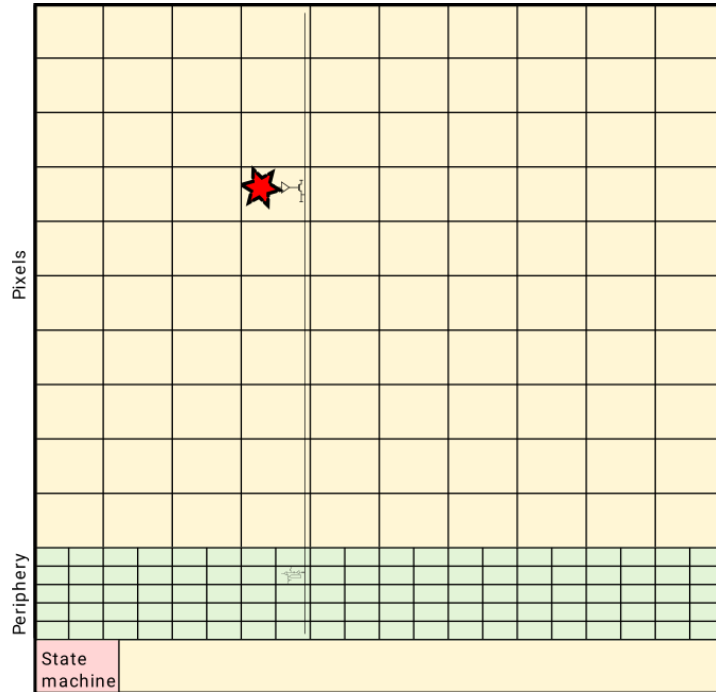
- Small prototype development culminates in MuPix7
- Scaling successful with MuPix8
- Foundry change necessary after MuPix9
- New foundry TSI with same base process (IBM 180nm)
- Large scale prototype MuPix10 and ATLASPix3 successfully produced with TSI

MuPix Architecture



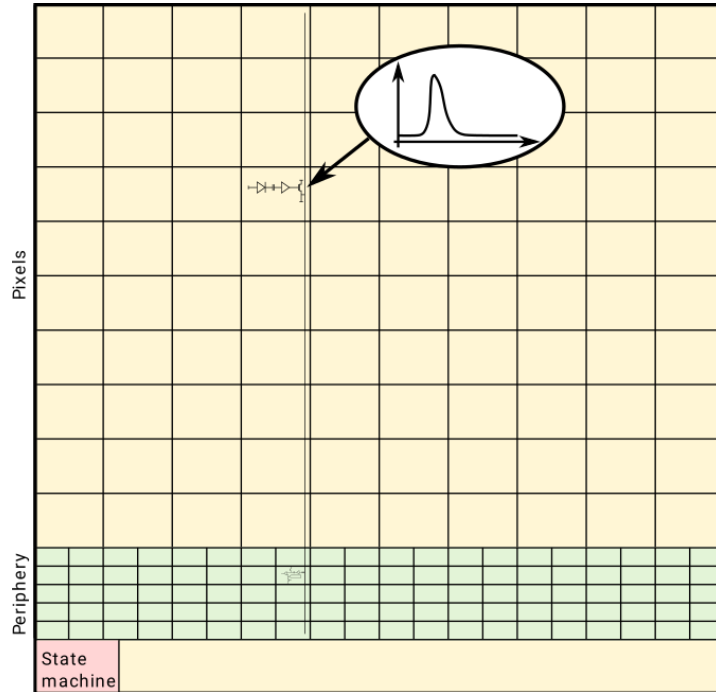
- Clear separation of analog and digital electronics
- 2 comparator design
- Tuning and masking available
- Priority encoder / column-drain readout
- Chip sub-divided into 3 matrices → 1 Data link each + 1 multiplexed link

The MuPix Principle



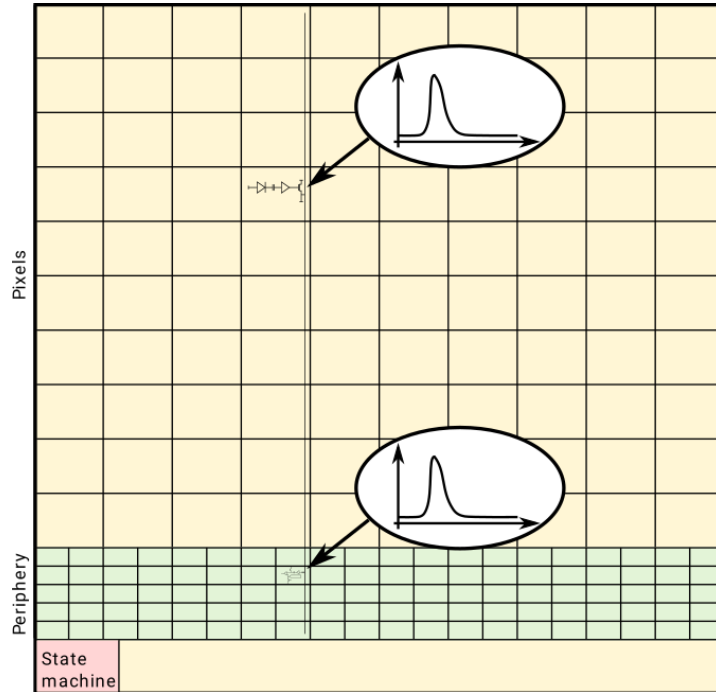
- Deposited charge amplified by in-pixel amplifier
- Source follower drives the signal to the periphery
- Digitisation in periphery
- Timestamp sampling
- Readout statemachine manages column-drain readout
- Data is send out via a 1.25 Gbit/s differential link

The MuPix Principle



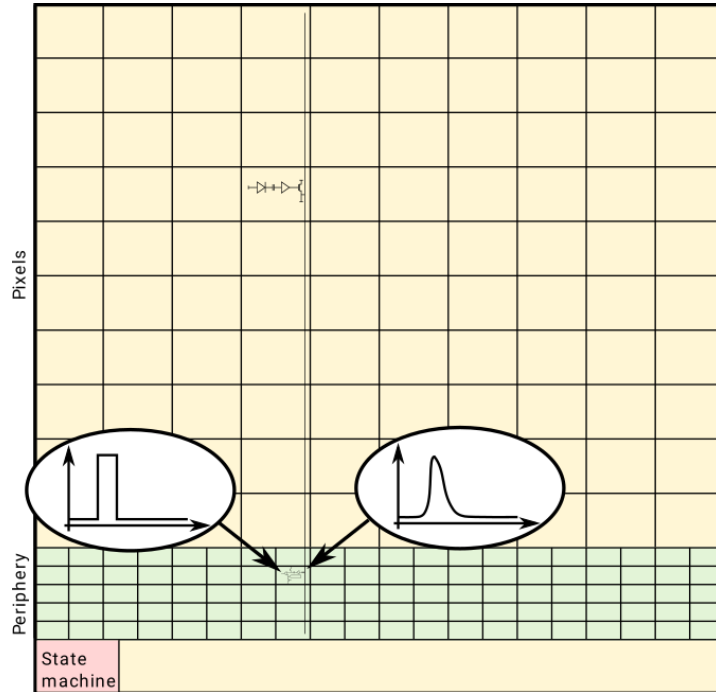
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The MuPix Principle



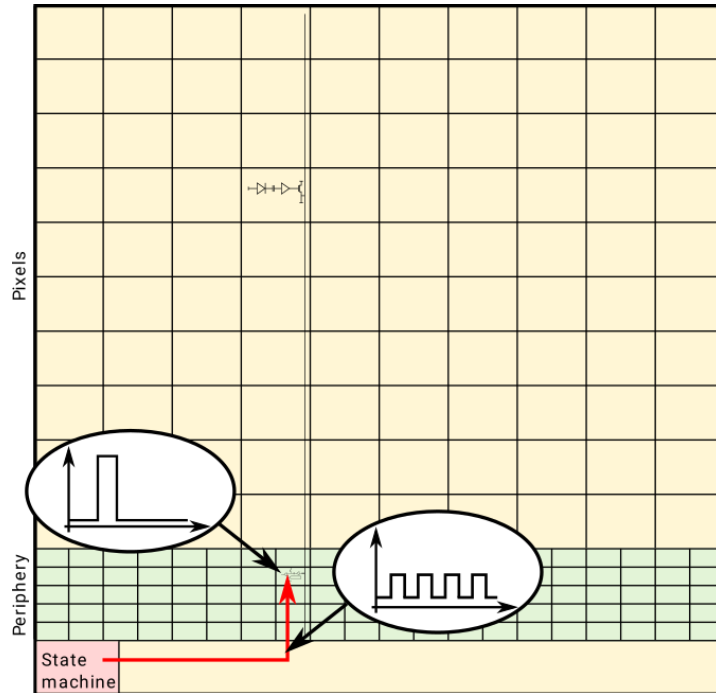
- Deposited charge amplified by in-pixel amplifier
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The MuPix Principle



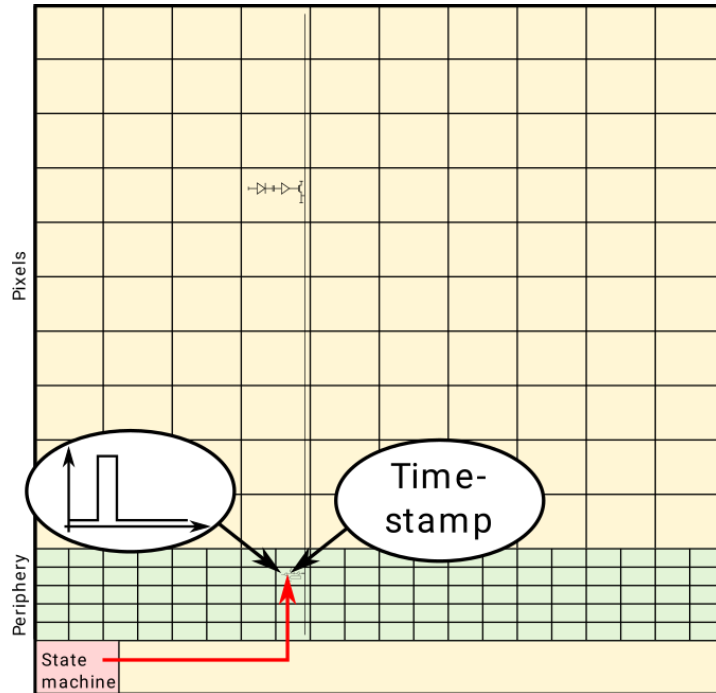
- Deposited charge amplified by in-pixel amplifier
- Source follower drives the signal to the periphery
- **Digitisation in periphery**
- Timestamp sampling
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The MuPix Principle



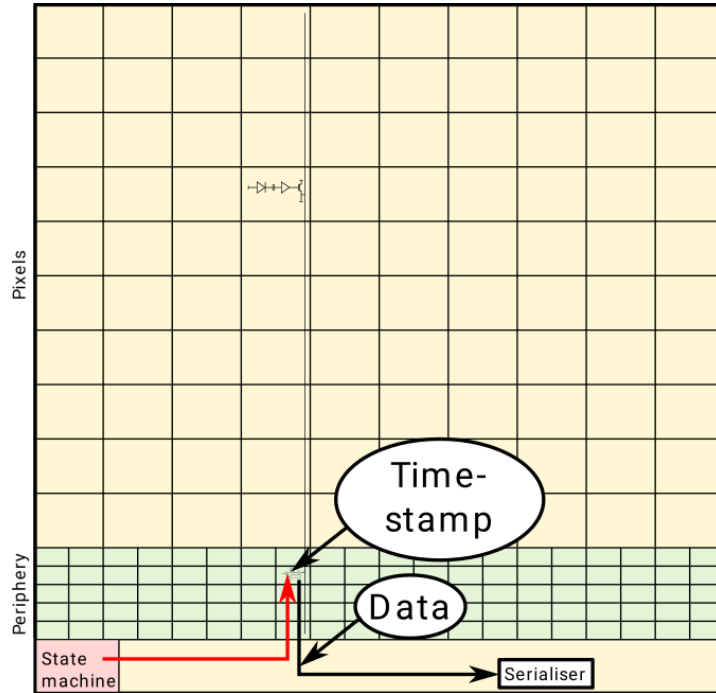
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The MuPix Principle



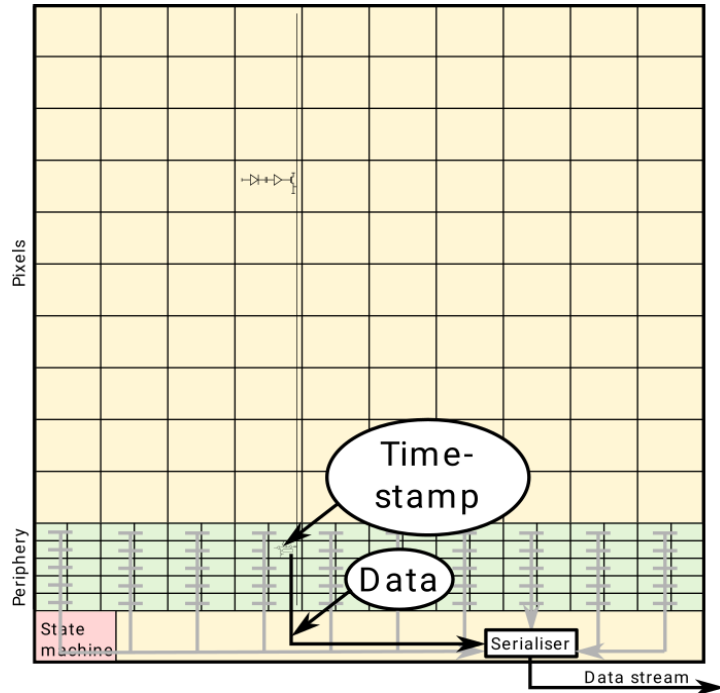
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The MuPix Principle



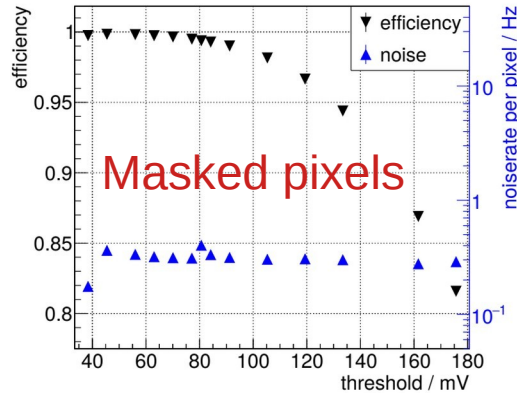
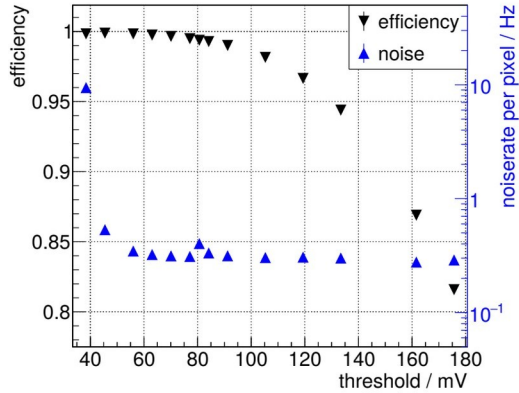
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The MuPix Principle

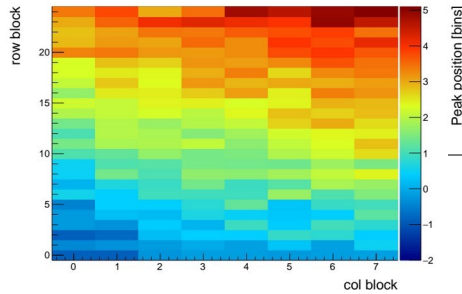
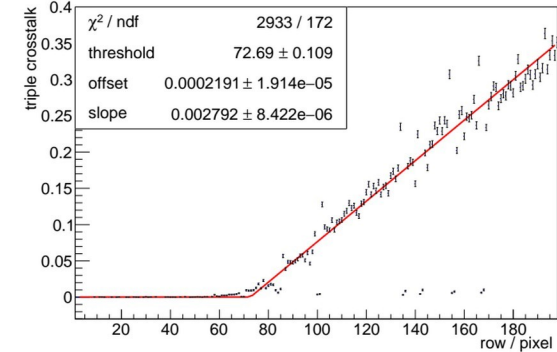


- Deposited charge amplified by in-pixel amplifier
- Source follower drives the signal to the periphery
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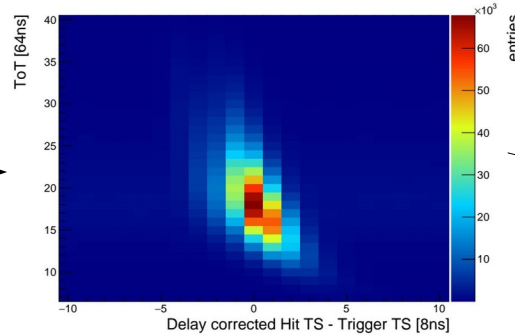
Latest Results - MuPix8



Signal Line Crosstalk



Pixel delay



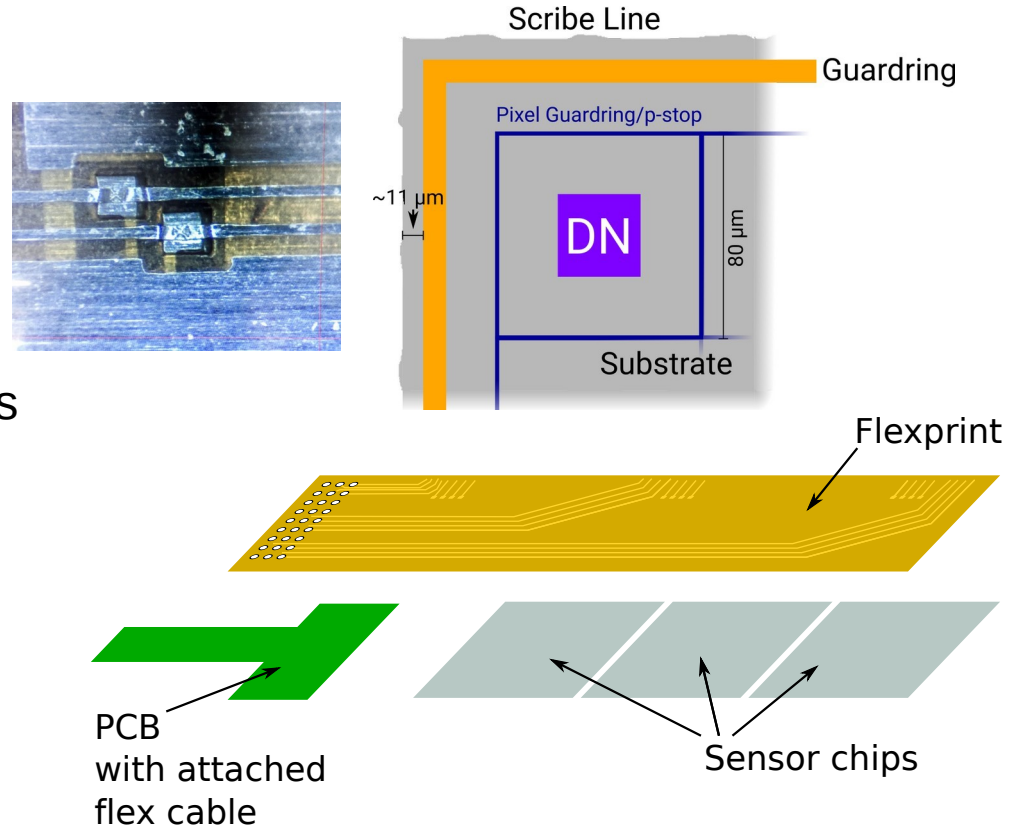
Timewalk

Raw time resolution	14 ns
+ Delay correction + Timewalk correction	6.5 ns

[arXiv:1905.09309]

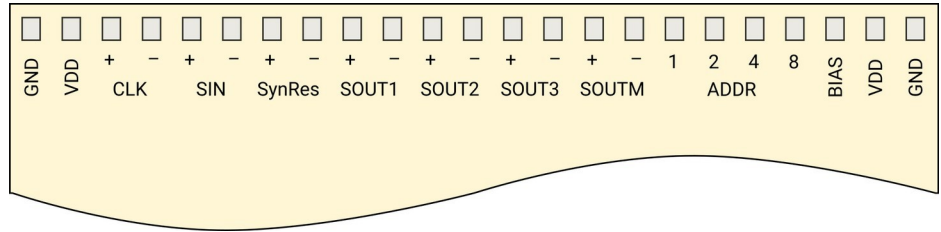
A MuPix Module

- Chips glued and SpTAB-bonded to flexprint
- No additional components!
 - 1.15‰ X_0 per layer
- Minimize dead space between the chips
 - Only 11 μm dead silicon outside the guardring
- Power consumption limited to 400 mW/cm² (Sensors+Flex)

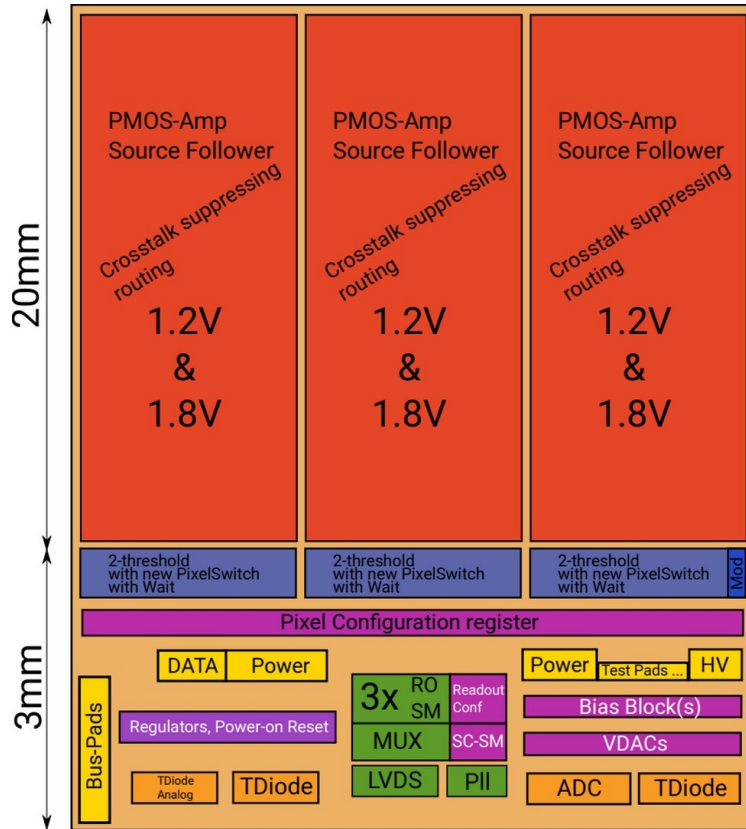


The Flexprint Environment

- 2 layer aluminum polyimide flexprint (LTU)
- Provides:
Power & HV
Differential Signal I/O
- Only 1 supply voltage, but no LDO-regulators!
- Minimise I/O
- Flex design rules define PadOut

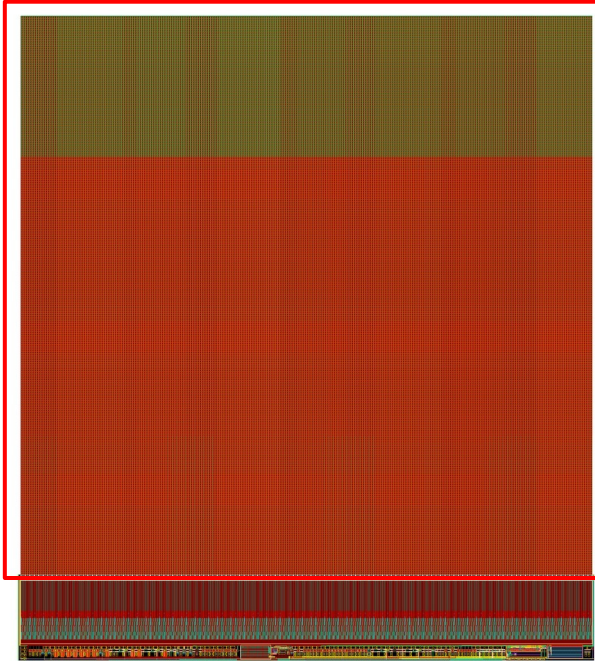


MuPix10 Design



- Module ready!
 - Pad Out compatible with flex
 - Chip size defined by mechanics
- Complete on-chip biasing:
 - triple redundant memory
 - bias and voltage DACs
- 1.2V voltage regulator
 - MuPix10 can be used for Module production

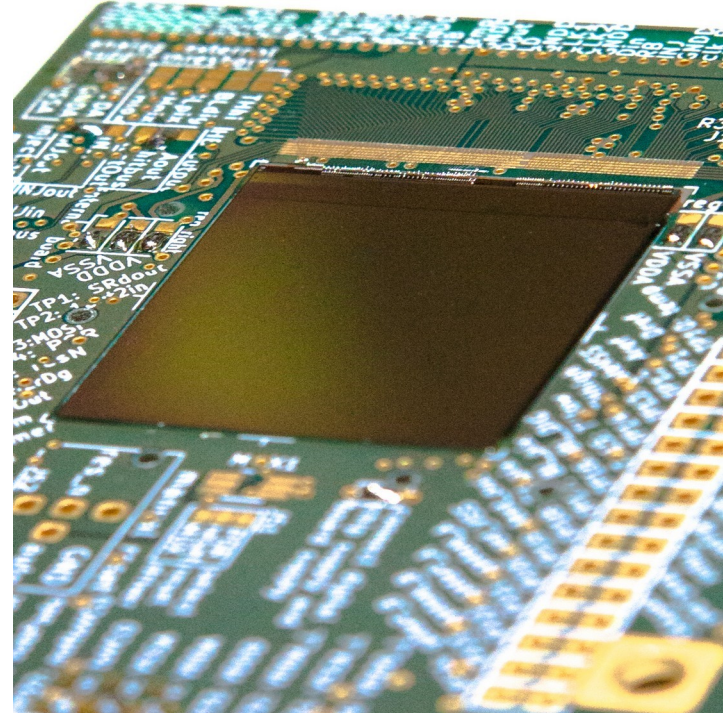
The MuPix10



Pixel size [μm^2]	80 x 80
Sensor size [mm^2]	20.66 x 23.18
Active size [mm^2]	20.48 x 20.0
Pixel matrix	256 x 250
Thickness [μm]	50
Substrate [Ωcm]	200-400
Data links	3+1
Data speed [Gbit/s]	1.25
Time-of-arrival [bits]	11
ToT [bits]	5
TS binning [ns]	8 (option for 1.6)

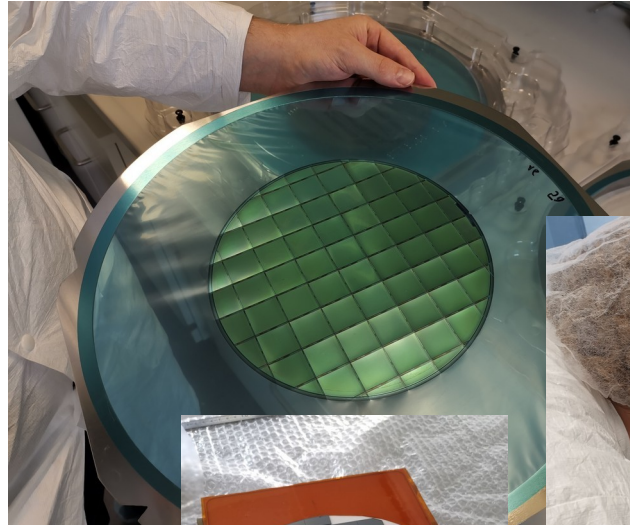
MuPix10 timeline

- December 2019:
Submission to TSI
- March 2020:
Wafer delivery
Send for post-processing
- March → May 2020:
Lock down in France and
Germany
- Mid of May 2020:
Receive first chips



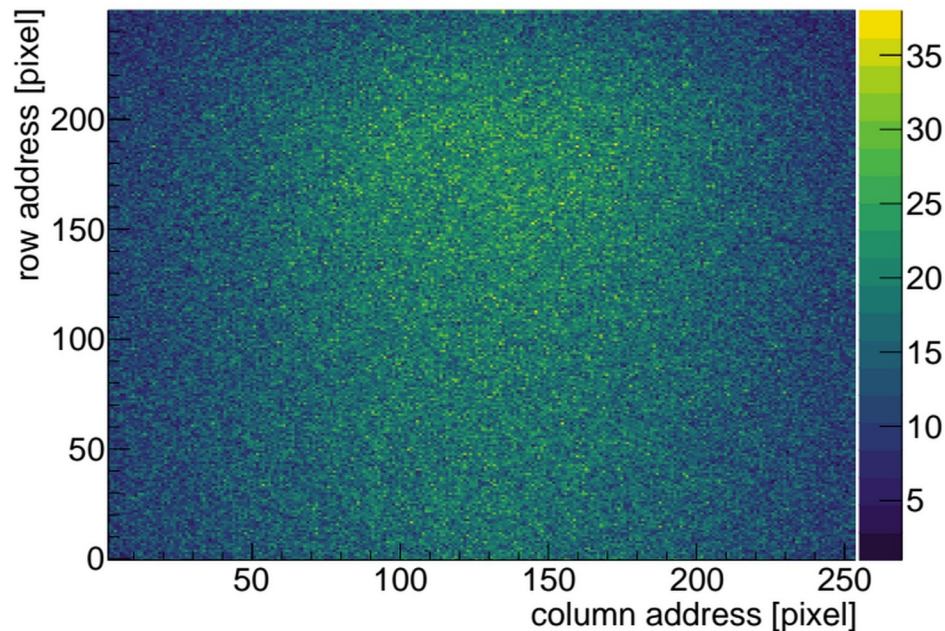
In-house Picking

- Diced Wafers delivered on tape (Company OPTIM)
- Equipment:
 - Vaccum chuck
 - Vaccum pick-up tool
 - Patience
- 3 thicknesses:
 - 625, 100 and 50 μm
- Picking yield very high: $>98\%$
- Effect on “electrical yield”?
- detailed study with probe card is pending



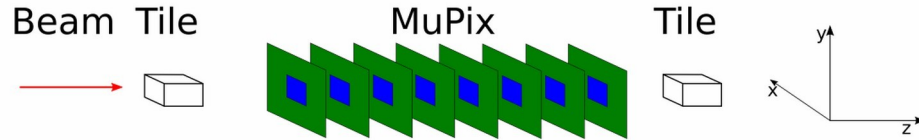
Commissioning & First results

- In the Lab:
Commissioning and Optimisation
with Injection or Sr90 and Fe55
- Breakdown @ -100V
→ 30-40um depletion
- Testbeam:
DESY 3 GeV e⁻
PSI 350 MeV π^+ , μ^+ , e⁺, (p⁺)
- MuPix10 works nicely

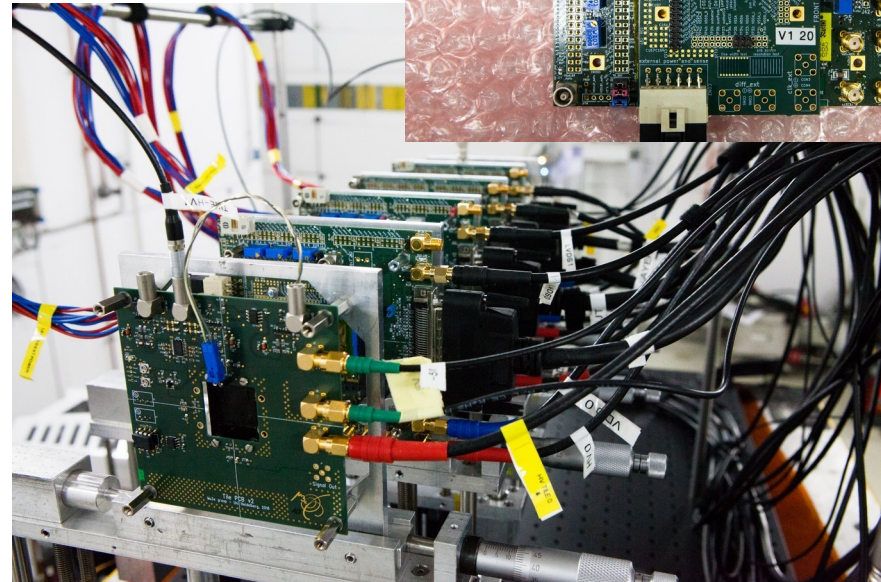


Hitmap DESY testbeam

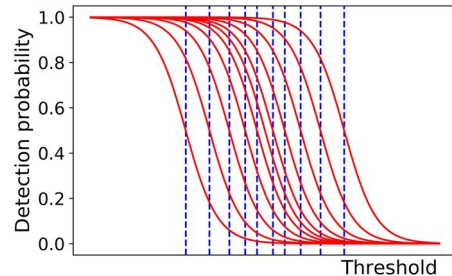
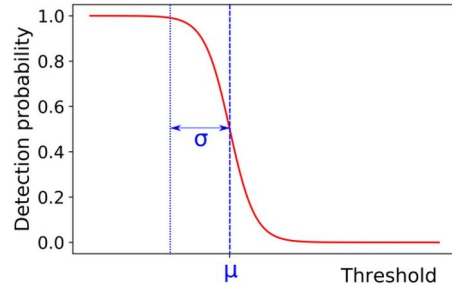
MuPix Telescope



- Co-Development of the DAQ
- Most common setup:
4 sensor layer (1 DUT)
coincidence of scintillating tiles
- Evolution of reference plains:
Mupix6, MuPix7, MuPix8, ATLASPix1,
ATLASPix3 and now MuPix10
- MuPix10 telescope used!

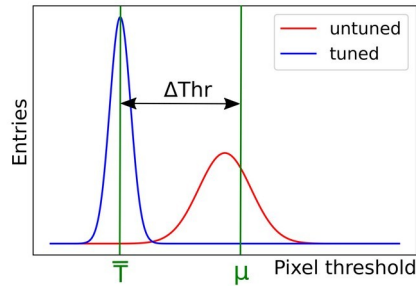
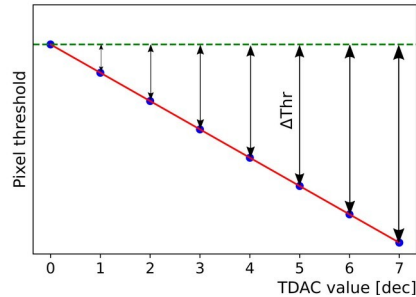


Tuning & Masking



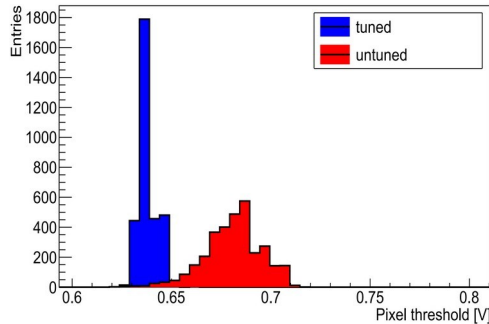
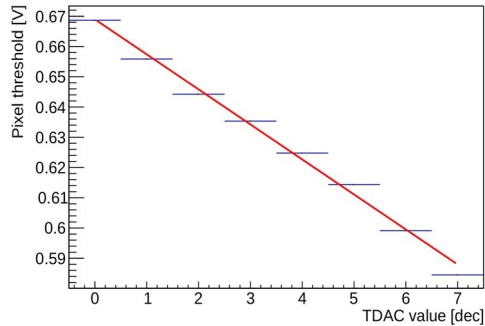
- Usage of the individual tuning and masking bits
- S-curve based tuning approach
- Data:
Injection of ~ 3000 e⁻ (fixed)
Threshold scanned
- Threshold dispersion:
Untuned RMS ~ 240 e⁻
Tuned RMS ~ 75 e⁻

Tuning & Masking



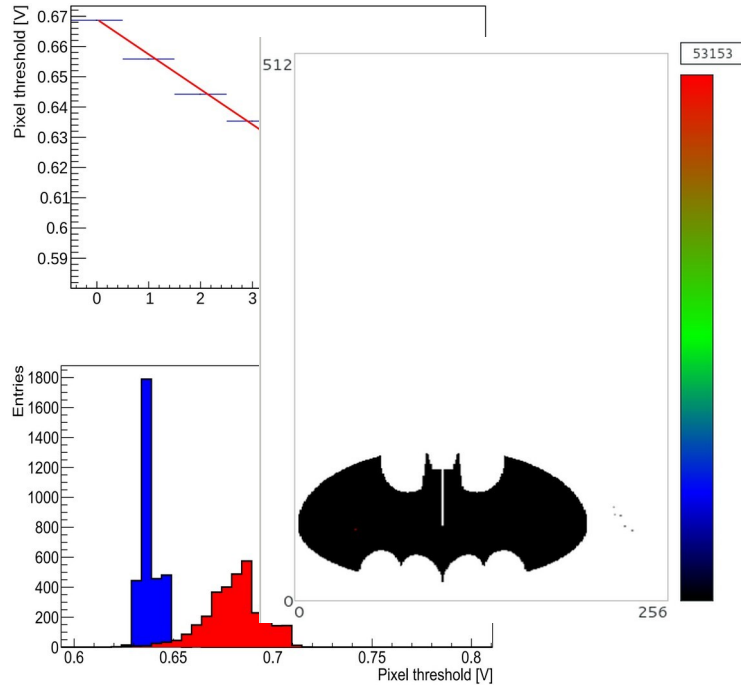
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Tuning & Masking



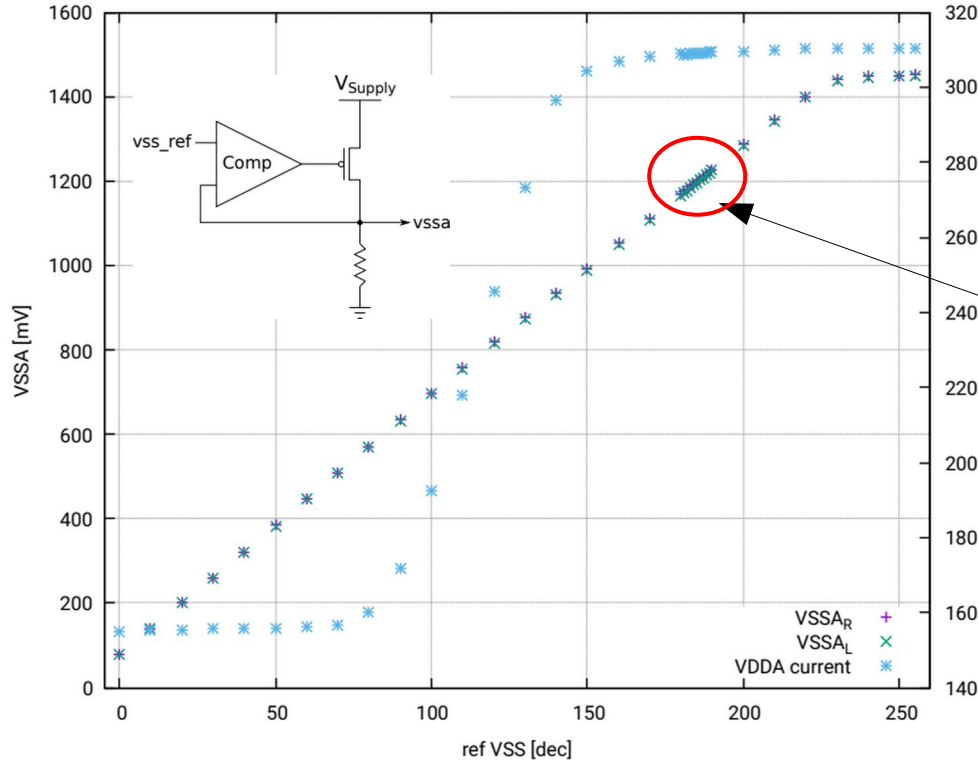
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Tuning & Masking



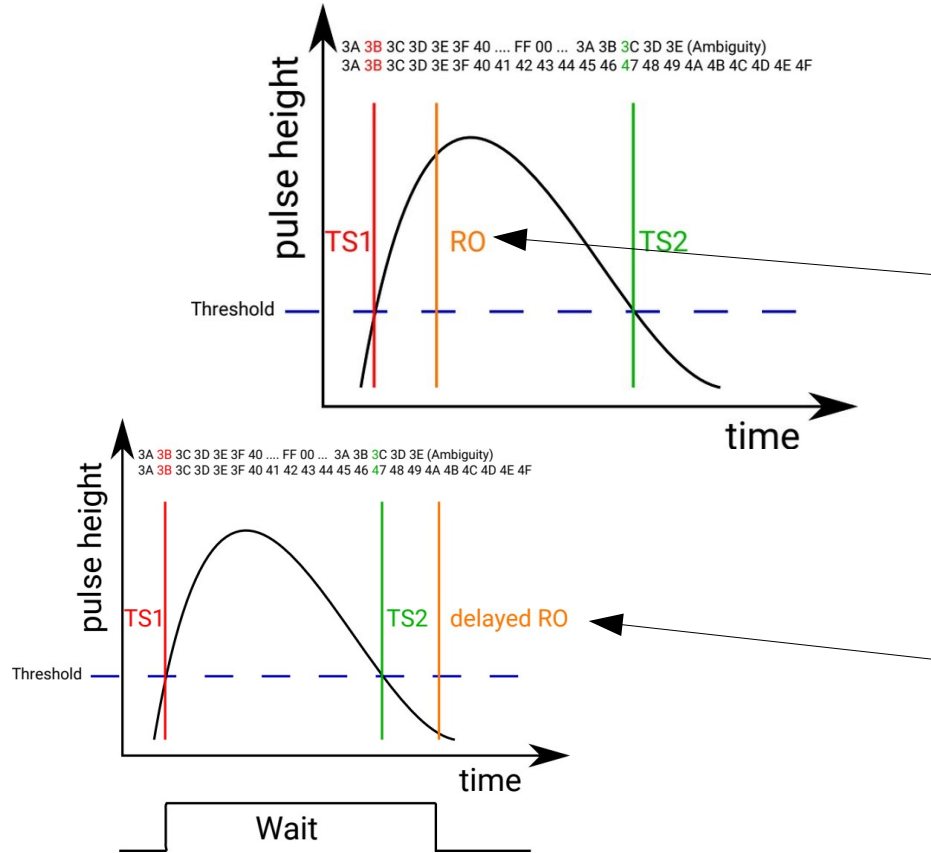
- Usage of the individual tuning and masking bits
- S-curve based tuning approach
- Data:
Injection of ~ 3000 e $^{-}$ (fixed)
Threshold scanned
- Threshold dispersion:
Untuned RMS ~ 240 e $^{-}$
Tuned RMS ~ 75 e $^{-}$
- Masking works nicely too

Vssa-Regulator



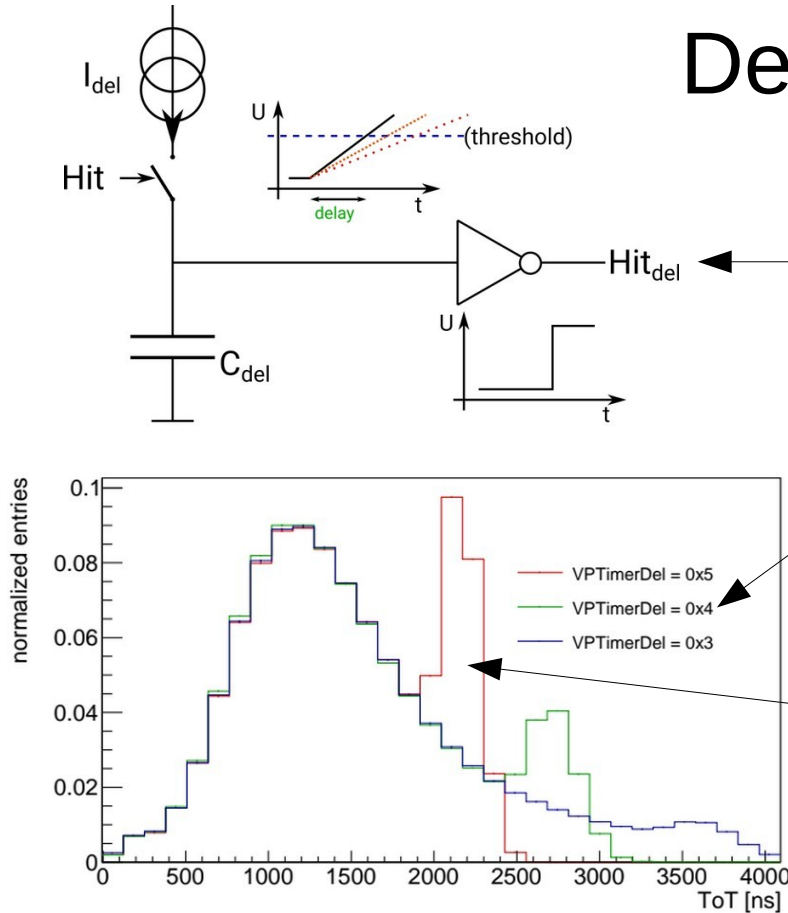
- Integral for module functionality with a single supply voltage
 - No detailed study yet
 - Dive into the cold water: the regulator works nicely
 - Even colder water: MuPix10 was operated successfully with a single supply voltage
- Power consumption: $\sim 220\text{mW/cm}^2$

ToT sampling



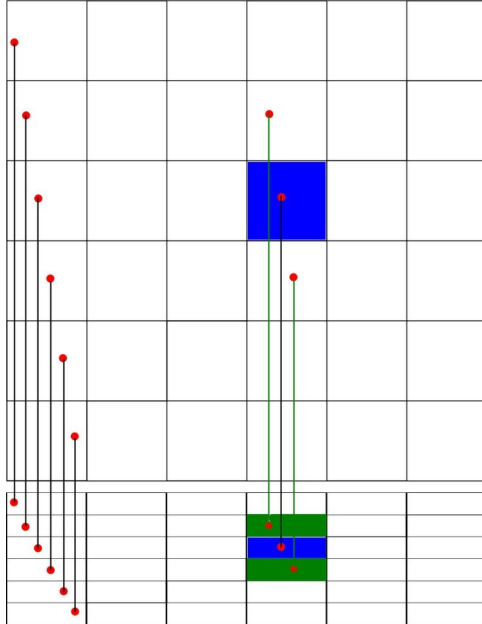
- ToT correction desired for offline data analysis
- Not foreseen on MuPix8
 - possible readout problem
 - ToT not fully sampled
- Easy Solution:
 - Wait for the pulse to end
 - scrambles the chronology of the data
- Additional complexity for the online sorting
- Better:
 - delay every hit by a constant time
 - Chronology conserved

Delay Circuit



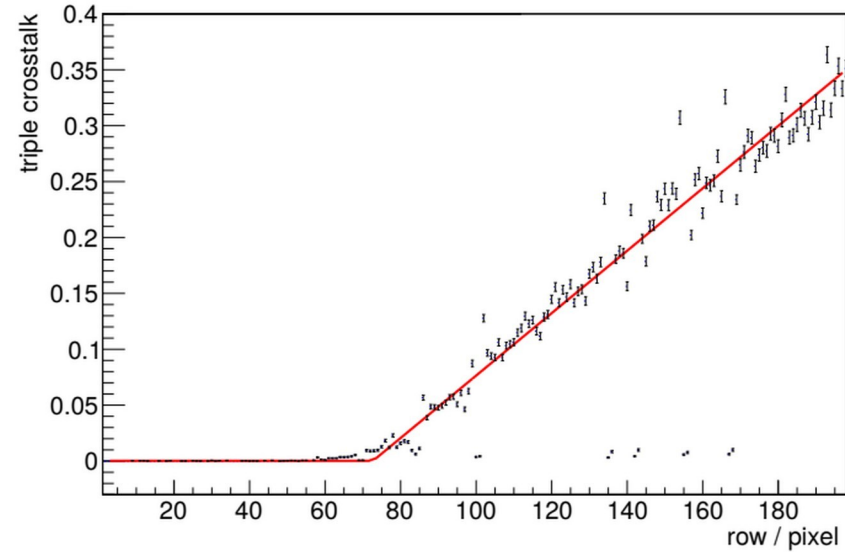
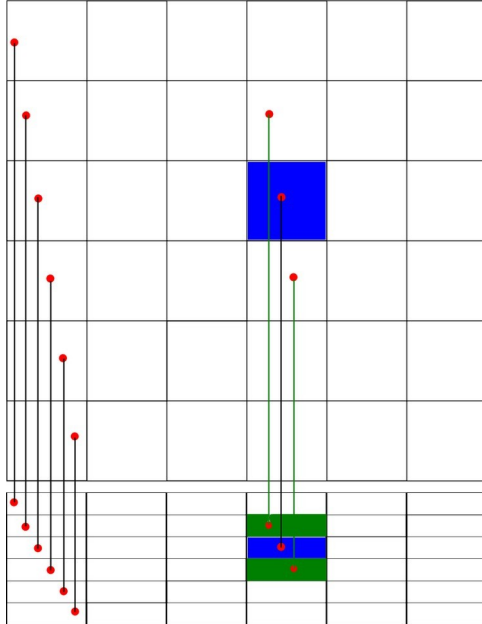
- Analogue Delay
Designed by Alena Weber(KIT)
- Contained in each digital pixel cell
- Delay programmable
- Delay measurable as maximum ToT
- Further idea: Hits with large ToTs do not gain from ToT correction
 - Limit the maximum ToT
 - More precision for low energy depositions
 - Works nicely!!

Signal Line Crosstalk - MuPix8



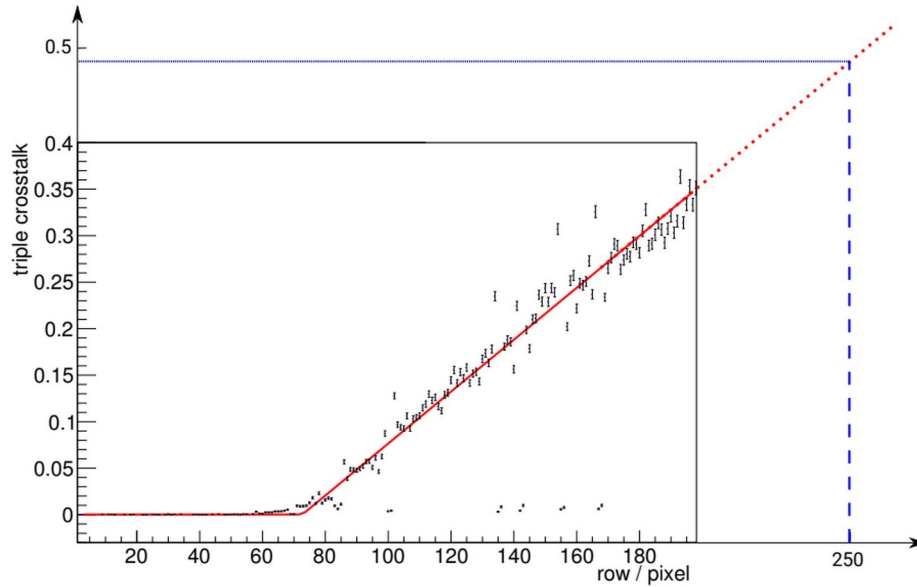
- Point-to-point connection
- Capacitive coupling to neighbouring lines (increases with length)
- Crosstalk can induce additional hits
 - Not easily distinguishable from charge sharing
 - Additional Readout load

Signal Line Crosstalk - MuPix8



Triple Crosstalk:
hit induced in both neighbouring lines

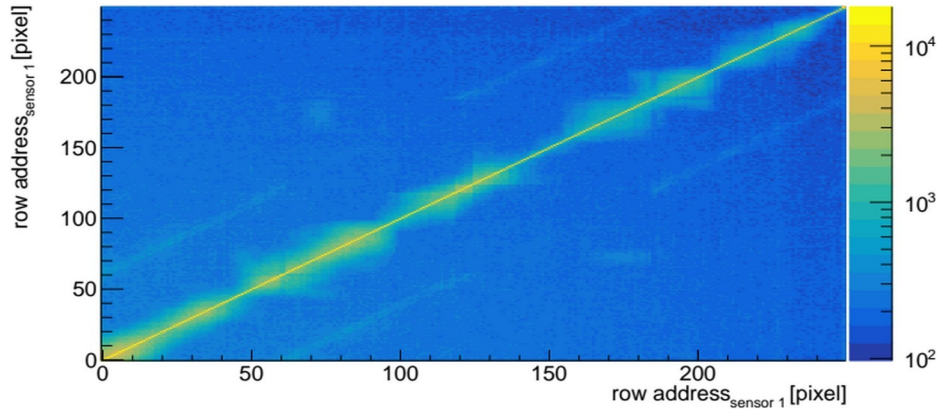
Crosstalk Extrapolation for MuPix10



Triple Crosstalk probability

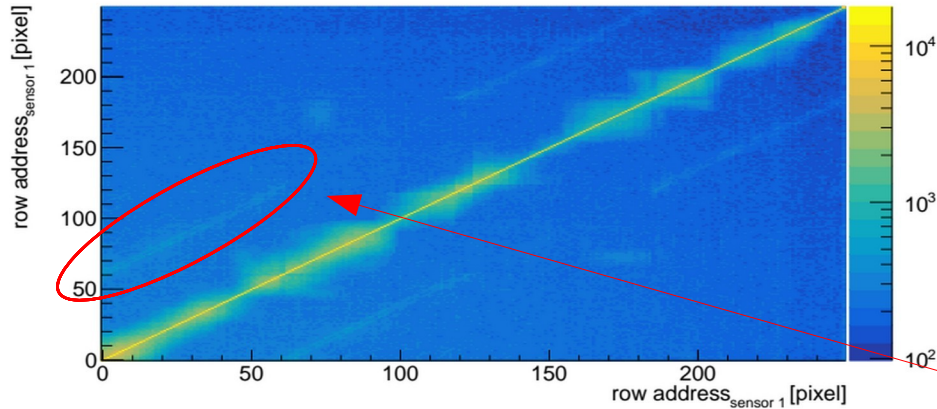
- Using the same routing density and scheme
 - Almost 48% crosstalk probability for the longest line
 - Penalty for high row addresses
 - Routing needs to adapt

Routing Optimisation - MuPix10



- Equalize but reduce crosstalk
→ minimise the length that two lines are neighbouring
($\frac{1}{4}$ of total length possible)
- ~12% triple crosstalk expected
- Make Crosstalk easily detectable
→ neighbouring signal lines are not neighbouring pixels

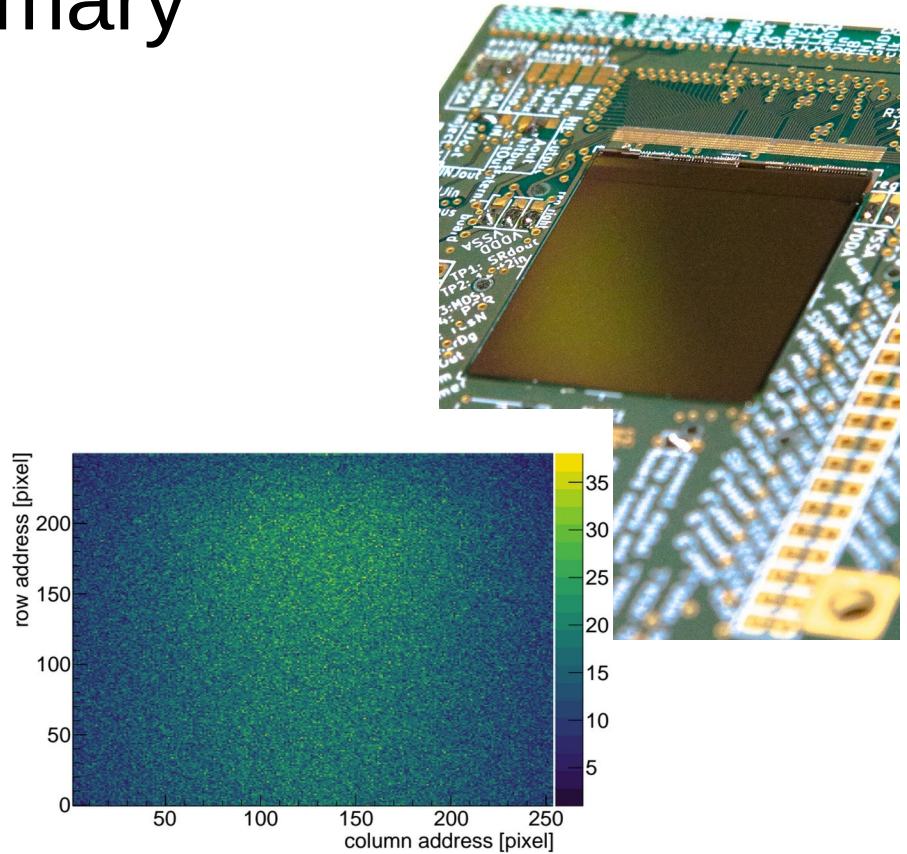
Routing Optimisation - MuPix10



- Equalize but reduce crosstalk
→ minimise the length that two line are neighbouring
($\frac{1}{4}$ of total length, 2cm)
 - ~12% triple crosstalk expected
- Make Crosstalk easily detectable
→ neighbouring signal lines are not neighbouring pixels
 - Crosstalk can be removed, possibly already during the data taking
- Even more improvement expected for MuPix11

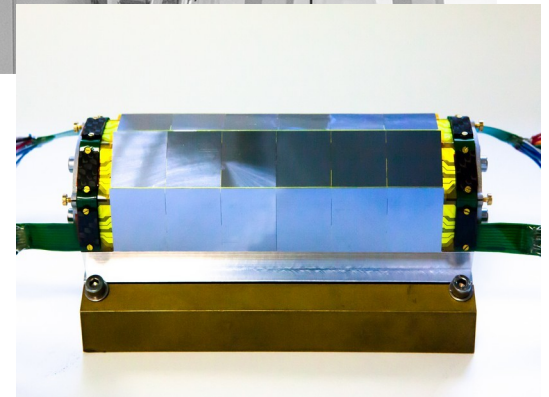
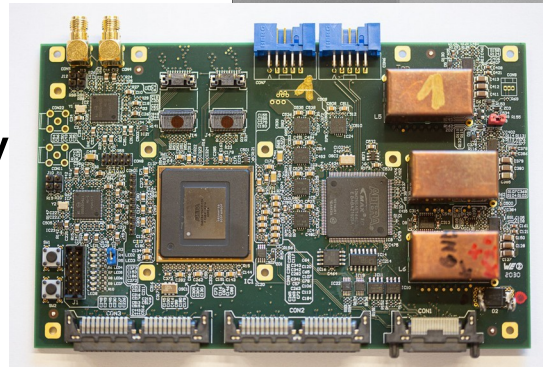
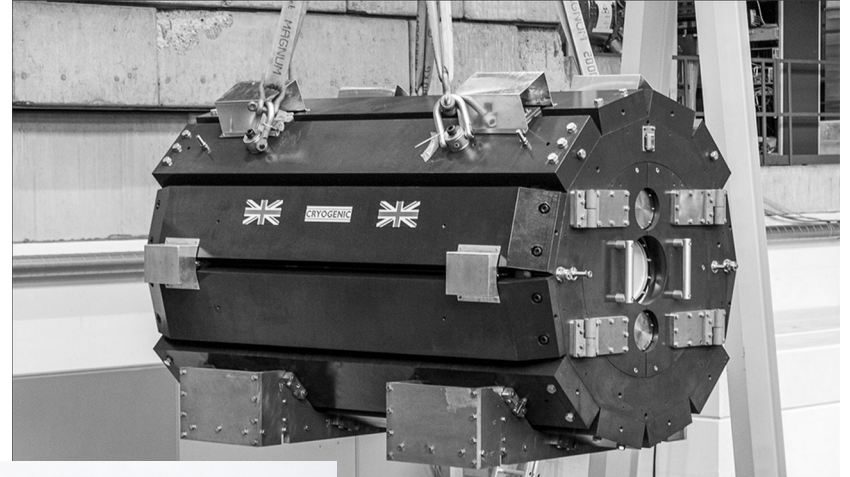
Summary

- MuPix10 is working nicely!
 - Full-scale
 - Module ready
- New features implemented successfully
 - Delay circuit, routing
- Final Submission:
MuPix11 Summer 2021



Mu3e Status

- Mu3e Magnet arrived at PSI and is currently cooling down
- Helium cooling system and tests are nicely progressing (Silicon Heater mock-up)
- Hardware of the readout chain available and heavily tested



End of the year plans

- Long beam time @PSI
- Tests within the magnet
- All sub-systems:
Pixel, Tile and Fibre
- Check of important paths of
the readout chain
- First 6 chip module
(not on flexprint)

